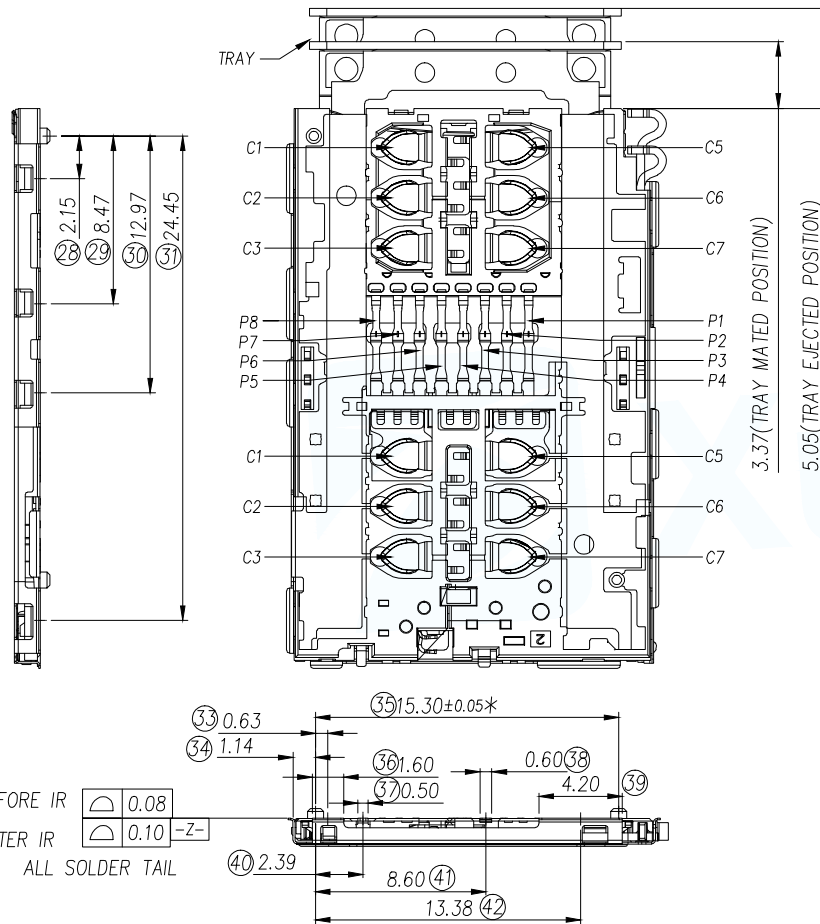


MANUFACTURE DWG		 东莞市讯普电子科技有限公司 DongGuan XunPu Electronics Co.,Ltd		
UNLESS OTHERWISE SPECIFIED TOLERANCES			TITLE: 1.35H 3in2 CONN. DOUBLE NANO SIM+Micro SD	
DECIMALS:	ANGLES:		PAR MCS-302L-C1 DWN CHKD APVD SCALE 1:1 UNIT:MM X.XX:±0.10	REV: A 
X.:±0.20	X'':±2"			
X.X:±0.15	.X':±1"			



NOTES:

1)PRODUCT SPECIFICATIONS:

VOLTAGE RATING:10V

CURRENT RATING:0.5A

INSULATON RESISTANCE:1000 MEG.OHM MIN

CONTACT RESISTANCE:INITIAL 50mΩ MaX;AFTER TEST R=30mΩ

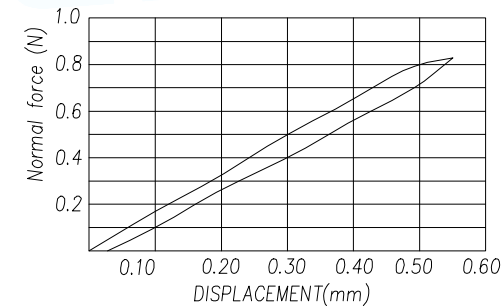
OPERATION TEMPERATURE:-40° TO +85°

DURABILITY:3000 CYCLES

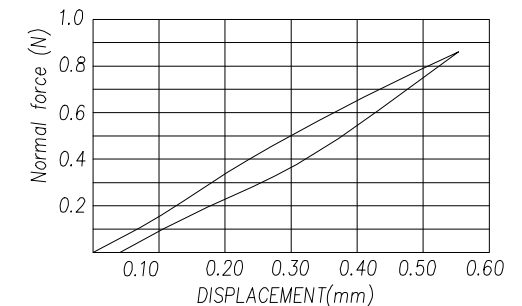
TRAY MATING FORCE:2~10N:TRAY UNMATING FORCE:4~10N

OPERATING FORCE:4~10N

THE RESORPTON DISTANCE OF THE TRAY:0.40mm MIN.

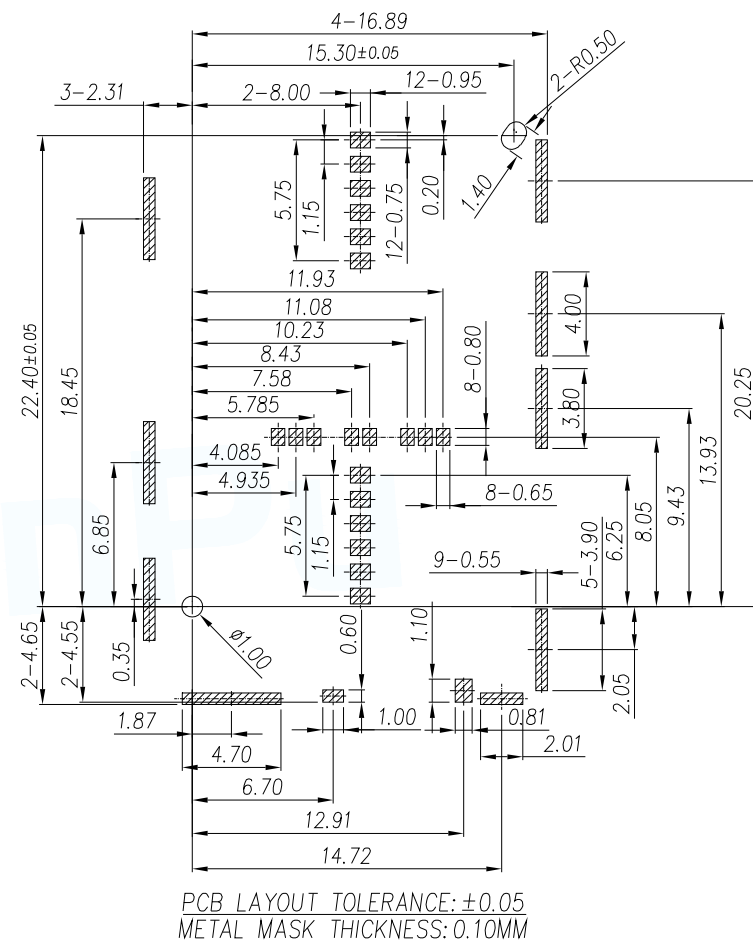


Nano Sim card Contact NF-Deflection Curve



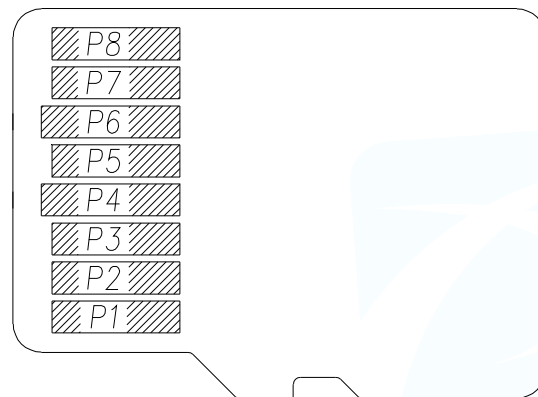
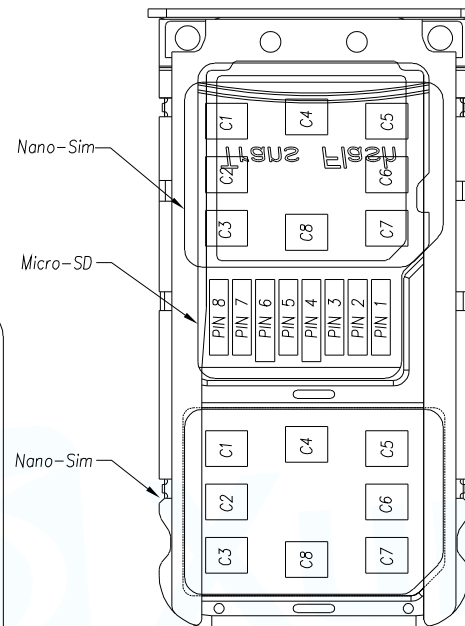
Micro SD Card Contact NF-Deflection Curve

MANUFACTURE DWG		 东莞市讯普电子科技有限公司 DongGuan XunPu Electronics Co.,Ltd			
UNLESS OTHERWISE SPECIFIED TOLERANCES			TITLE:1.35H 3in2 CONN.DOUBLE NANO SIM+Micro SD		
			PAR	MCS-302L-C1	
DECIMALS:	ANGLES:		DWN	Lucas	
X.:±0.50	X.':±5°		CHKD	Ethan	
X.X:±0.30	X.X':±3°		APVD	Jacob	
X.XX:±0.15	X.XX':±1°		SCALE1:1	UNIT:MM	
		CUSTOMER COPY	SIZE:A4	SHEET:1F1	REV:A

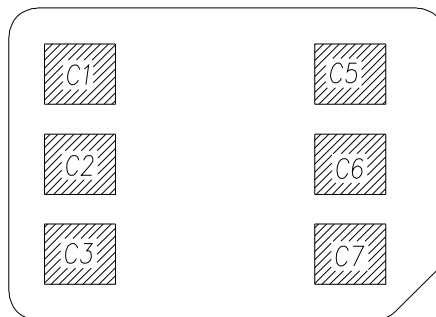


- | | | | | | |
|---------------------------------------|---------|---|---|---|--|
| MANUFACTURE DWG | |  东莞市讯普电子科技有限公司
DongGuan XunPu Electronics Co.,Ltd | | | |
| UNLESS OTHERWISE SPECIFIED TOLERANCES | |  | TITLE: 1.35H 3in2 CONN.
DOUBLE NANO SIM+Micro SD | | |
| | | | PAR | MCS-302L-C1 | |
| DECIMALS: | ANGLES: | | DWN | | |
| X.:±0.20 | X'.:±2° | | CHKD | | |
| X.X:±0.15 | .X':±1° | APVD | | | |
| X.XX:±0.10 | | SCALE1:1 | UNIT:MM |  | |
| | | CUSTOMER COPY | SIZE:A4 | SHEET:1F1 REV:A | |

BOTTOM VIEW



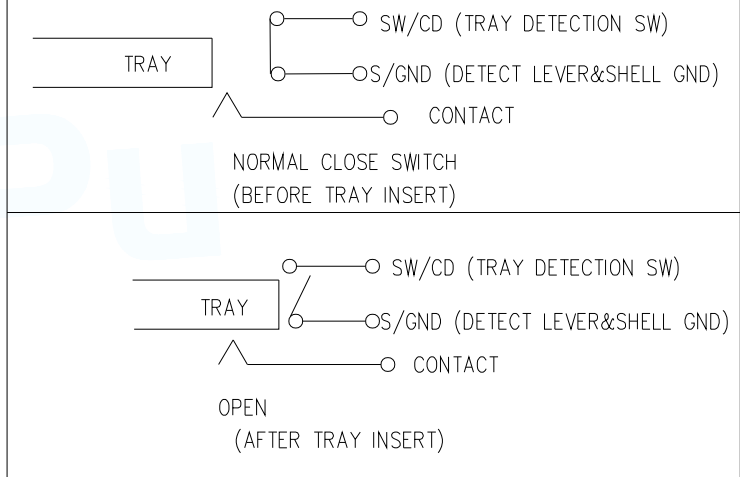
Micro SD CARD ELECTRICAL



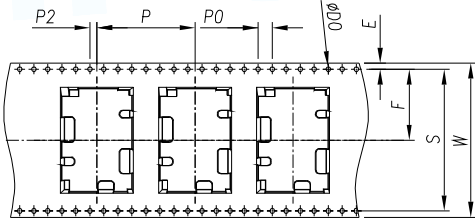
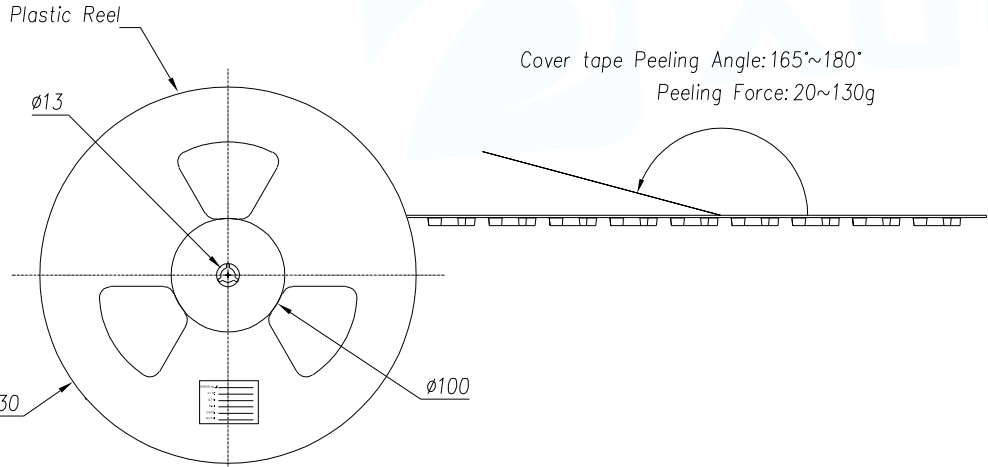
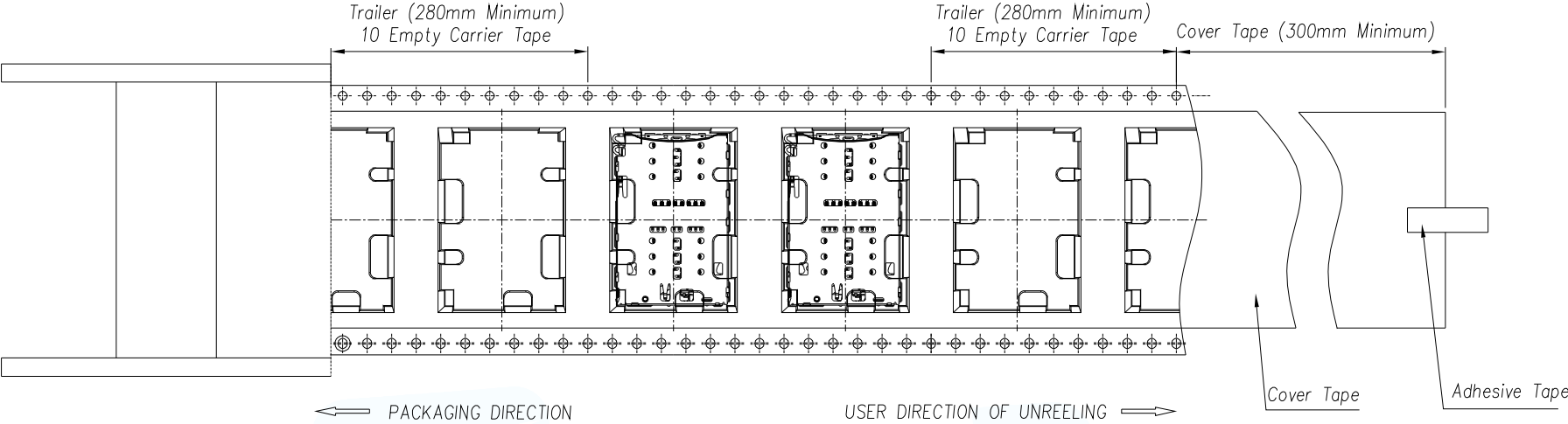
NANO SIM CARD ELECTRICAL

ITEM	FUNCTION
Micro SD CARD	
P1	DAT2 OF MSD
P2	CD/DAT3 OF MSD
P3	CMD OF MSD
P4	VDD OF MSD
P5	CLK OF MSD
P6	VSS OF MSD
P7	DAT0 OF MSD
P8	DAT1 OF MSD
NANO SIM CARD	
C1	VCC OF SIM
C2	RST OF SIM
C3	CLK OF SIM
C5	GND OF SIM
C6	VPP OF SIM
C7	DATA OF SIM

CIRCUIT DIAGRAM FOR DETECT SWITCHES



MANUFACTURE DWG		 东莞市讯普电子科技有限公司 DongGuan XunPu Electronics Co.,Ltd	
UNLESS OTHERWISE SPECIFIED TOLERANCES			
DECIMALS:	ANGLES:	TITLE: 1.35H 3in2 CONN. DOUBLE NANO SIM+Micro SD	
X.:±0.20	X'.:±2°	PAR	MCS-302L-C1
X.X:±0.15	.X':±1°	DWN	
X.XX:±0.10		CHKD	
CUSTOMER COPY		APVD	
		SCALE:1:1	UNIT:MM
		SIZE:A4	SHEET:1F1
			REV:A



P	28.00±0.10
P0	4.00±0.10
P2	2.00±0.10
D0	1.50±0.10
E	1.75±0.10
F	20.20±0.10
S	40.40±0.10
W	44.00±0.10

1	MCS-302L-C1	800	6	9.95	4800	340X340X335
ITEM	PRODUCT NO:	QTY/REEL	REEL/CARTON	Kg/CARTON	QTY/CARTON	CARTON SIZE

MANUFACTURE DWG

UNLESS OTHERWISE SPECIFIED TOLERANCES

DECIMALS:

ANGLES:

X.:±0.20

X'.:±2°

X.X:±0.15

.X':±1°

X.XX:±0.10



东莞市讯普电子科技有限公司
DongGuan XunPu Electronics Co.,Ltd

TITLE: 1.35H 3in2 CONN.
DOUBLE NANO SIM+Micro SD

PAR

MCS-302L-C1

DWN

CHKD

APVD

SCALE1:1

UNIT:MM



CUSTOMER COPY

SIZE:A4

SHEET:1F1

REV:A